

HM6226

Dual 2:1 High-Speed USB2.0 (480Mbps) SPDT Analog Switch with True Isolation

Descriptions

The HM6226 is a bidirectional low-power dual port, high-speed, USB 2.0 analog switch with integrated protection for USB Type-C™ systems. The device is configured as a dual 2:1 or 1:2 switch. It is optimized for use with the USB 2.0 DP/DM lines in a USB Type-C™ system. The device is capable of true isolation. Even when COM+/- overrides VCC, very little current will flow back to the supply.

The HM6226 has low bit-to-bit skew and high channel-to-channel noise isolation, and is compatible with various standards, such as high-speed USB 2.0 (480Mbps). Each switch is bidirectional and offers little or no attenuation of the high-speed signals at the outputs. Its bandwidth is wide enough to pass high-speed USB 2.0 differential signals (480 Mb/s) with good signal integrity.

GPIO control of SEL 1.8V logic compatible. The HM6226 is available in UQFN 1.4x1.8-10L with Pb-free and Halogen-free making it a perfect candidate for mobile and space constrained applications.

Order Information

Package		Part Number	Top-Side Marking
UQFN 1.4x1.8 -10L	Tape and Reel	HM6226	A26 /GYW

Features

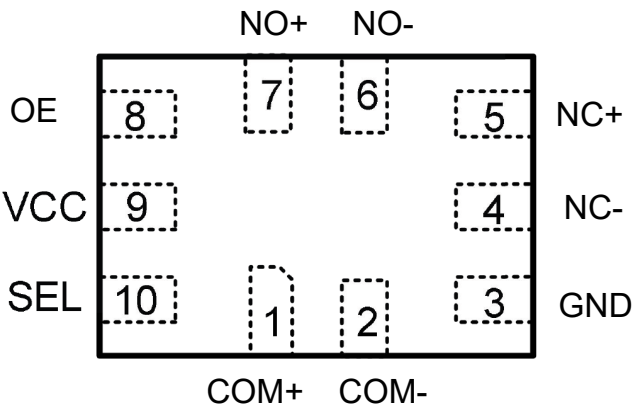
- Pin-to-Pin **FSUSB42, NX3DV42, WAS7227, SGM7227, RS2228, BL1532**
- Low On-resistance, Ron=1.5Ω when VCC =5V
- 1.8V Logic Compatible Control Pin
- COM+/- Overrides VCC to Achieve True Isolation Even When Supply Is Dead
- High Off-Isolation: **-100dB @ 100KHz**
- Low Channel-to-Channel Crosstalk: **-97dB @ 100KHz**
- High Bandwidth (-3dB @800MHz) Suitable for USB2.0 High-Speed Routing
- Low Quiescent Current (<2uA) With Very Wide Supply Range (1.5V ~ 5.5V)

Applications

- Anywhere a USB Type-C™ or Micro-B Connector is Used
- Mobile Phones, Tablets and Notebooks

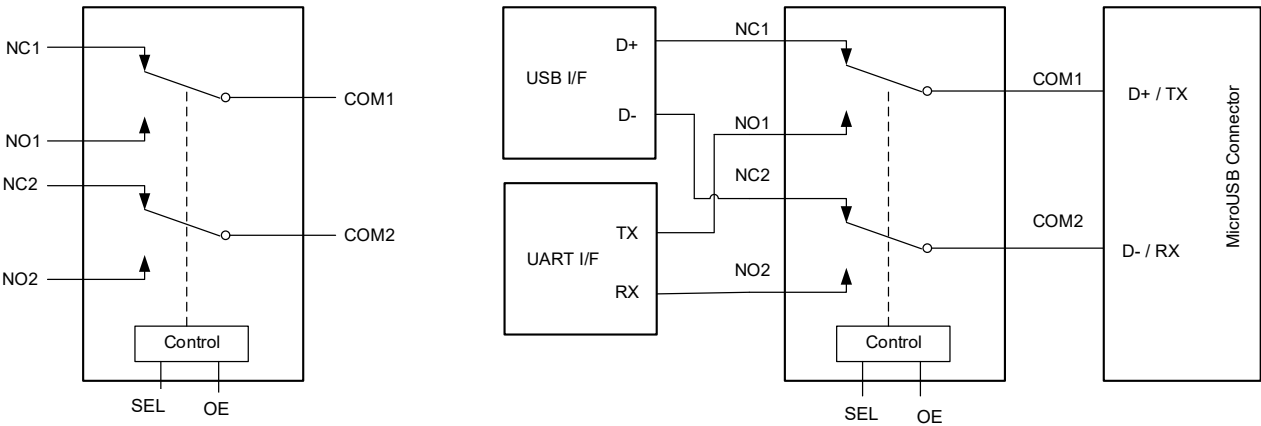
Functions and Pin Configuration

Pin Number	Symbol	Descriptions
1,2	COM _x	Common Signal Ports
3	OE	Active Low
8	GND	Ground
4,5	NC _x	Analog/Digital Signal Ports (Normally closed)
6,7	NO _x	Analog/Digital Signal Ports (Normally open)
9	VCC	Single Power Supply
10	SEL	Logic Input Selection



Function Descriptions

Input SEL	Function
0	NC1=COM1 and NC2=COM2
1	NO1=COM1 and NO2=COM2



Absolute Maximum Ratings ⁽¹⁾

Parameter	Symbol	Value	Unit
Supply Voltage	V _{CC}	-0.3 ~ 6.5	V
Control Input Voltage	V _{IN}	-0.3 ~ 6.5	V
Continuous Current Through NO, NC, COM		±100	mA
Peak Current Through NO, NC, COM (pulsed at 1ms 50% duty cycle)		±200	mA
Storage Temperature Range	T _{STG}	-55 ~ 150	°C
Junction Temperature under Bias	T _J	150	°C
Lead Temperature (Soldering, 10 seconds)	T _L	260	°C
Power Dissipation	P _D	250	mW

Recommend operating ratings ⁽²⁾

Parameter	Symbol	Value	Unit
Supply Voltage Operating	V _{CC}	1.5 ~ 5.5	V
Control Input Voltage	V _{IN}	-0.3 ~ 5.5	V
Input Signal Voltage	V _{COM}	-0.3 ~ 5.5	V
Operating Temperature	T _A	-40 ~ 85	°C
Thermal Resistance	R _{θJA}	360	°C/W

Note:

1. "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress only rating and operation of the device at these or any other conditions beyond those indicated in the operational sections of this specification is not implied.

DC Electronics Characteristics (Ta=25°C, VCC=3.3V, unless otherwise noted)

Parameter	Symbol	Conditions	Min.	Typ.	Max.	Unit
Input logic high level	V _{IH}	VCC: 3.3 ~ 5.5V	1.6			V
		VCC: 1.5 ~ 3.3V	1.4			V
Input logic low level	V _{IL}	VCC: 3.3 ~ 5.5V			0.6	V
		VCC: 1.5 ~ 3.3V			0.4	V
Supply quiescent current	I _{CC}	I _{COM} =0, V _{IN} =0 or V _{IN} =VCC			1.0	uA
Increase in I _{CC} per input	I _{CC} T	I _{COM} =0, VCC=4.5V V _{IN} >1.8 or V _{IN} <0.5			1.0	uA
Off state leakage from COM _x to NC _x (or NO _x)	I _{COMx}	V _{COM} = 5.5V, V _{NC(or NO)} = 0V			±2.0	uA
On-Resistance	R _{ON1}	V _{COM} =0 ~ 0.5V, I _{COM} =30mA		3.0	3.5	Ω
	R _{ON2}	V _{COM} =0.5 ~ 2.0V, I _{COM} =30mA		3.6	3.9	Ω
	R _{ON3}	V _{COM} =2.0 ~ 4.0V, I _{COM} =30mA		2.5	3.5	Ω
	R _{ON4}	V _{COM} =4.0 ~ 5.5V, I _{COM} =30mA		1.5	1.8	Ω
On-Resistance Flatness	R _{FLAT1}	V _{COM} =0 ~ 0.5V, I _{COM} =30mA		0.7		Ω
	R _{FLAT2}	V _{COM} =0.5 ~ 2.0V, I _{COM} =30mA		0.5		Ω
	R _{FLAT3}	V _{COM} =2.0 ~ 4.0V, I _{COM} =30mA		1.6		Ω
	R _{FLAT4}	V _{COM} =4.0 ~ 5.5V, I _{COM} =30mA		0.3		Ω
On-Resistance Matching Between Channels	Δ R _{ON}	V _{COM} =0~5.5V, I _{COM} =30mA,		0.1	0.2	Ω

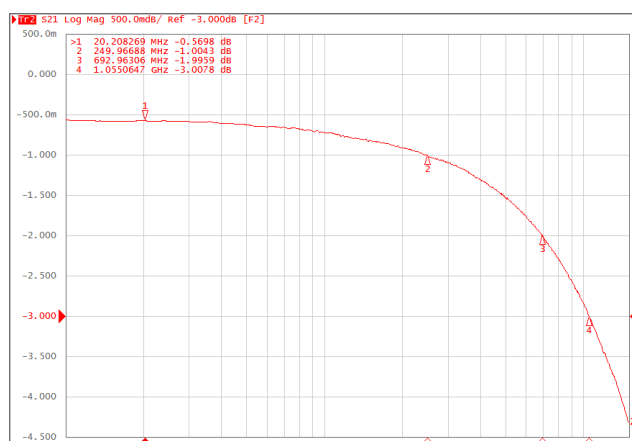
AC Electronics Characteristics (Ta=25°C, VCC=3.3V, unless otherwise noted)

Parameter	Symbol	Conditions	Min.	Typ.	Max.	Unit
Turn-On Time	T _{ON}	V _{COM} =1.5V, C _L =35pF, R _L =50Ω		200		ns
Turn-Off Time	T _{OFF}	V _{COM} =1.5V, C _L =35pF, R _L =50Ω		200		ns
Break-Before-Make time	T _{BBM}	V _{COM} =1.5V, C _L =35pF, R _L =50Ω		500		ns
-3dB Bandwidth	BW	R _L =50Ω, C _L =0pF		800		MHz
Off isolation	OIRR	F=1KHz, R _L =50Ω		-81		dB
		F=10KHz, R _L =50Ω		-80		dB
Crosstalk	Xtalk	F=1KHz, R _L =50Ω		-83		dB
		F=10KHz, R _L =50Ω		-82		dB
Total Harmonic Distortion	THD	F=20Hz to 20KHz V _{COM} =600mVp-p @R _L =32Ω,		-80		dB

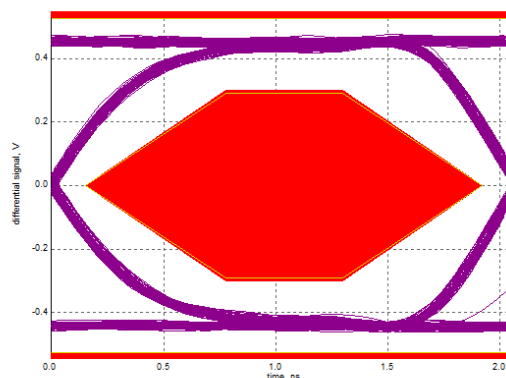
Capacitance (Ta=25°C, VCC=3.3V, unless otherwise noted)

Parameter	Symbol	Conditions	Min.	Typ.	Max.	Unit
Off capacitance	C _{OFF}	F=100KHz		5		pF
On capacitance	C _{ON}	F=100KHz		7		pF

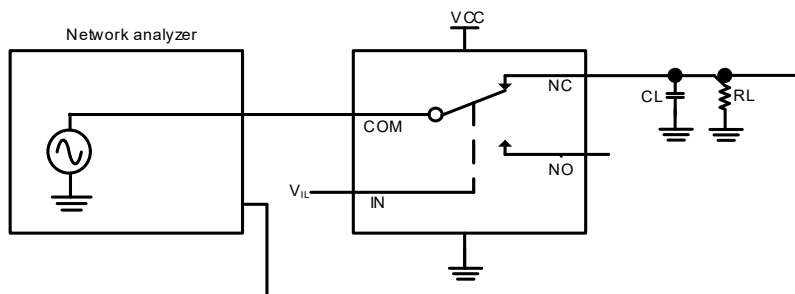
Typical Characteristics (Ta=25°C, VCC=3.3V, unless otherwise noted)



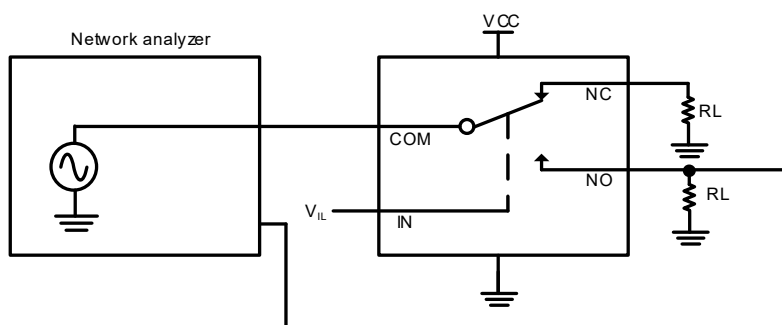
Bandwidth



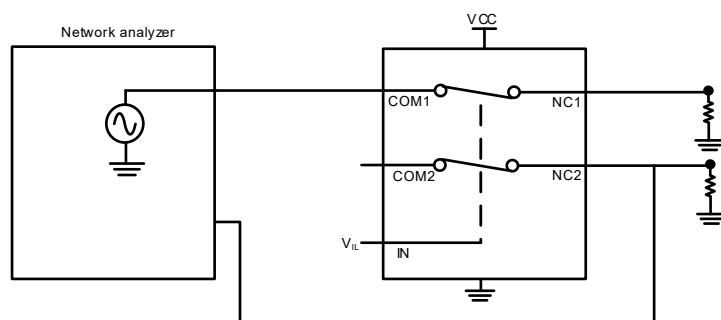
Eye Diagram (480Mbps)



Bandwidth



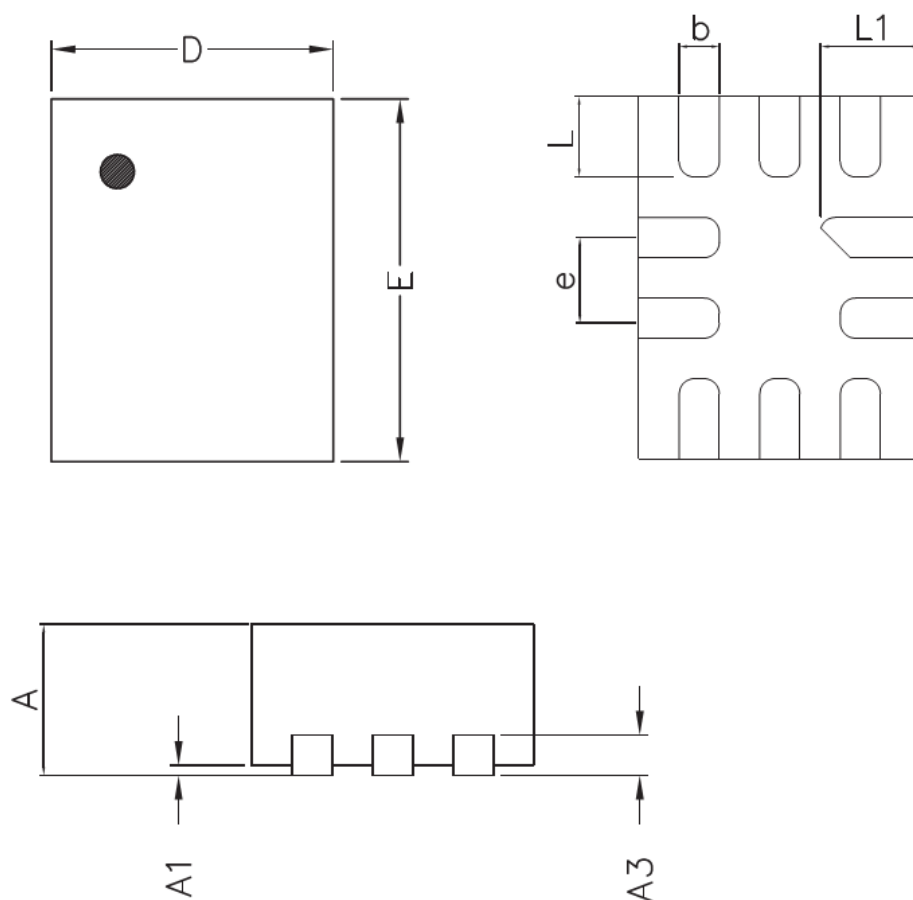
Off isolation



Crosstalk

Package Outline Dimensions

QFN1418-10L



Symbol	Dimension in Millimeters	
	Min.	Max.
A	0.450	0.550
A1	0.000	0.050
A3	0.152 Ref.	
D	1.350	1.450
E	1.750	1.850
b	0.150	0.250
e	0.400 Typ.	
L	0.350	0.450
L1	0.450	0.550